

1N746 thru 1N759A, -1 and 1N4370 thru 1N4372A, -1 DO-35

Silicon 500 mW Zener Diodes

DESCRIPTION

The popular 1N746 thru 1N759A and 1N4370 thru 1N4372A series of 0.5 watt Zener Voltage Regulators provides a selection from 2.4 to 12 volts in standard 5% or 10% tolerances as well as tighter tolerances identified by different suffix letters on the part number. These glass axial-leaded DO-35 Zeners are also available with an internal-metallurgical-bond option by adding a "-1" suffix. These are also available in JAN, JANTX, and JANTXV military qualifications. Microsemi also offers numerous other Zener products to meet higher and lower power applications.

IMPORTANT: For the most current data, consult *MICROSEMI's* website: http://www.microsemi.com

DO-35 (DO-204AH)

FEATURES

- JEDEC registered 1N746 thru 1N759A and 1N4370 thru 1N4372A series
- Internal metallurgical bond option available by adding a "-1" suffix
- Also available in JAN, JANTX, and JANTXV qualifications per MIL-PRF-19500/127 by adding the JAN, JANTX, or JANTXV prefixes to part numbers for desired level of screening as well as –1" suffix; (e.g. JANTX1N751A-1, JANTXV1N758C-1, etc.)
- Military Surface Mount equivalents also available in DO-213AA by adding a UR-1 suffix in addition to the JAN, JANTX, and JANTXV prefix; e.g. JANTX1N962BUR-1 (see separate data sheet)
- Commercial Surface Mount equivalents available as MLL746 to MLL759A and MLL4370 to MLL4372A including the "-1" suffix in the DO-213AA MELF style package (consult factory for others)
- DO-7 glass body axial-leaded Zener equivalents are also available

APPLICATIONS / BENEFITS

- Regulates voltage over a broad operating current and temperature range
- Selection from 2.4 to 12 V
- Standard voltage tolerances are plus/minus 5% with A suffix identification and 10 % with no suffix
- Tight tolerances available in plus or minus 2% or 1% with C or D suffix respectively
- Flexible axial-lead mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method 1020
- Minimal capacitance (see Figure 3)
- Inherently radiation hard as described in Microsemi MicroNote 050

MAXIMUM RATINGS

- Operating and Storage temperature: -65°C to +175°C
- Thermal Resistance: 250 °C/W junction to lead at 3/8 (10 mm) lead length from body, or 310 °C/W junction to ambient when mounted on FR4 PC board (1 oz Cu) with 4 mm² copper pads and track width 1 mm, length 25 mm
- Steady-State Power: 0.5 watts at T_L ≤ 50°C 3/8 inch (10 mm) from body or 0.48 W at T_A ≤ 25°C when mounted on FR4 PC board as described for thermal resistance above (also see Figure 1)
- Forward voltage @200 mA: 1.1 volts
- Solder Temperatures: 260 °C for 10 s (max)

MECHANICAL AND PACKAGING

- CASE: Hermetically sealed axial-lead glass DO-35 (DO-204AH) package
- TERMINALS: Leads, tin-lead plated solderable per MIL-STD-750, method 2026
- POLARITY: Cathode indicated by band. Diode to be operated with the banded end positive with respect to the opposite end for Zener regulation
- MARKING: Part number
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams
- See package dimensions on last page



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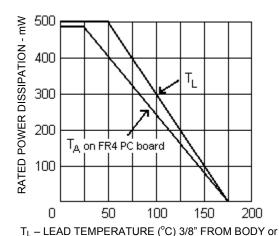
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| ELECTRICAL CHARACTERISTICS* @ 25°C | | | | | | | |
|------------------------------------|--|--------------------------|---|--|------------|-----------------------------|------------------------------------|
| JEDEC TYPE NO. | NOMINAL ZENER VOLTAGE | ZENER TEST CURRENT | MAXIMUM ZENER IMPEDANCE | MAXIMUM REVERSE CURRENT I_R @ $V_R = 1$ VOLT | | MAXIMUM ZENER CURRENT | TYPICAL TEMP COEFF. OF ZENER |
| (NOTE1) | V _Z @ I _{ZT} (NOTE 2) | I _{ZT} | Z _{ZT} @ I _{ZT} (NOTE 3) | @25°C | @+150°C | I _{ZM} (NOTE 4) | VOLTAGE ανz |
| | VOLTS | mA | OHMS | μ Α | μ Α | mA | %/°C |
| 1N4370 | 2.4 | 20 | 30 | 100 | 200 | 150 | 085 |
| 1N4371 | 2.7 | 20 | 30 | 75 | 150 | 135 | 080 |
| 1N4372 | 3.0 | 20 | 29 | 50 | 100 | 120 | 075 |
| 1N746 | 3.3 | 20 | 28 | 10 | 30 | 110 | 066 |
| 1N747 | 3.6 | 20 | 24 | 10 | 30 | 100 | 058 |
| 1N748 | 3.9 | 20 | 23 | 10 | 30 | 95 | 046 |
| 1N749 | 4.3 | 20 | 22 | 2 | 30 | 85 | 033 |
| 1N750 | 4.7 | 20 | 19 | 2 | 30 | 75 | 015 |
| 1N751 | 5.1 | 20 | 17 | 1 | 20 | 70 | +/010 |
| 1N752 | 5.6 | 20 | 11 | 1 | 20 | 65 | +.030 |
| 1N753 | 6.2 | 20 | 7 | .1 | 20 | 60 | +.049 |
| 1N754 | 6.8 | 20 | 5 | .1 | 20 | 55 | +.053 |
| 1N755 | 7.5 | 20 | 6 | .1 | 20 | 50 | +.057 |
| 1N756 | 8.2 | 20 | 8 | .1 | 20 | 45 | +.060 |
| 1N757 | 9.1 | 20 | 10 | .1 | 20 | 40 | +.061 |
| 1N758 | 10.0 | 20 | 17 | .1 | 20 | 35 | +.062 |
| 1N759 | 12.0 | 20 | 30 | .1 | 20 | 30 | +.062 |

* JEDEC Registered Data

- NOTE 1: Standard tolerance on JEDEC types shown is +/- 10%. Suffix letter A denotes +/- 5% tolerance; suffix letter C denotes +/- 2%; and suffix letter D denotes +/- 1% tolerance.
- NOTE 2: Voltage measurements to be performed 20 seconds after application of dc test current.
- NOTE 3: Zener impedance derived by superimposing on I_{ZT} , a 60 cps, rms ac current equal to 10% I_{ZT} (2mA ac). See MicroNote 202 for typical zener Impedance variation with different operating currents.
- **NOTE 4:** Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

GRAPHS



T_A on FR4 PC BOARD
FIGURE 1

POWER DERATING CURVE

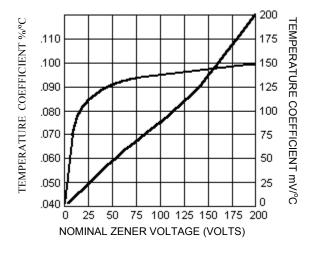


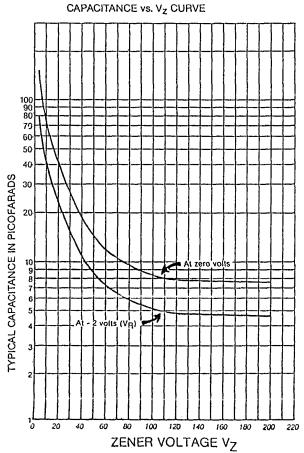
FIGURE 2
ZENER VOLTAGE TEMPERATURE
COEFFICIENT vs. ZENER VOLTAGE

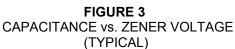
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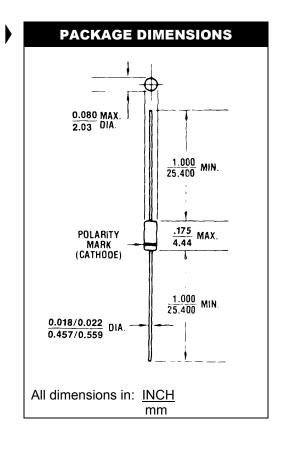


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